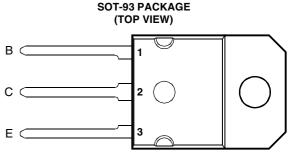
TIP33, TIP33A, TIP33B, TIP33C NPN SILICON POWER TRANSISTORS

BOURNS®

- Designed for Complementary Use with the TIP34 Series
- 80 W at 25°C Case Temperature
- 10 A Continuous Collector Current
- 15 A Peak Collector Current
- Customer-Specified Selections Available



Pin 2 is in electrical contact with the mounting base.

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
	TIP33		80	
Collector base veltage $(L = 0)$	TIP33A	V	100	v
Collector-base voltage $(I_E = 0)$	TIP33B	Сво	120	v
	TIP33C		140	
Collector emitter veltore (I = 0)	TIP33		40	
	TIP33A	N	60	V
Collector-emitter voltage ($I_B = 0$)	TIP33B	V _{CEO}	80	
	TIP33C		100	
Emitter-base voltage		V _{EBO}	5	V
Continuous collector current	-	Ι _C	10	А
Peak collector current (see Note 1)		I _{CM}	15	А
Continuous base current		I _B	3	А
Continuous device dissipation at (or below) 25°C case temperature (see Note 2	P _{tot}	80	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note	P _{tot}	3.5	W	
Unclamped inductive load energy (see Note 4)		½LI _C ²	62.5	mJ
Operating junction temperature range		Тj	-65 to +150	°C
Storage temperature range		T _{stg}	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds		ΤL	250	°C

NOTES: 1. This value applies for $t_p \le 0.3$ ms, duty cycle $\le 10\%$.

2. Derate linearly to $150^{\circ}C$ case temperature at the rate of 0.64 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 28 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)} = 0.4$ A, $R_{BE} = 100 \Omega$, $V_{BE(off)} = 0$, $R_S = 0.1 \Omega$, $V_{CC} = 20$ V.

PRODUCT INFORMATION

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TIP33, TIP33A, TIP33B, TIP33C NPN SILICON POWER TRANSISTORS



electrical characteristics at 25°C case temperature

PARAMETER			TEST CONDITIONS			ТҮР	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage			TIP33	40			
		$l_{0} = 30 \text{ mA}$ $l_{0} = 0$	I _B = 0	TIP33A	60			v
				TIP33B	80			,
				TIP33C	100			
		V _{CE} = 80 V	$V_{BE} = 0$	TIP33			0.4	
I _{CES}	Collector-emitter cut-off current	V _{CE} = 100 V	$V_{BE} = 0$	TIP33A			0.4	mA
		V _{CE} = 120 V	$V_{BE} = 0$	TIP33B			0.4	ША
		V _{CE} = 140 V	$V_{BE} = 0$	TIP33C			0.4	
I _{CEO}	Collector cut-off	V _{CE} = 30 V	I _B = 0	TIP33/33A			0.7	mA
	current	V _{CE} = 60 V	I _B = 0	TIP33B/33C			0.7	ША
1	Emitter cut-off	V _{EB} = 5 V	I _C = 0				1	mA
I _{EBO}	current						'	ША
h	Forward current	$V_{CE} = 4 V$	I _C = 1 A	(see Notes 5 and 6)	40			
h _{FE}	transfer ratio	$V_{CE} = 4 V$	I _C = 3 A		20		100	
Varia	Collector-emitter	I _B = 0.3 A	I _C = 3 A	(see Notes 5 and 6)			1	V
V _{CE(sat)}	saturation voltage	I _B = 2.5 A	$I_{\rm C} = 10 {\rm A}$				4	v
V_{BE}	Base-emitter	$V_{CE} = 4 V$	I _C = 3 A	(see Notes 5 and 6)			1.6	V
	voltage	$V_{CE} = 4 V$	$I_{\rm C} = 10 {\rm A}$		Ň		3	v
h _{fe}	Small signal forward	V _{CE} = 10 V	I _C = 0.5 A	f = 1 kHz	20			
	current transfer ratio	VCE - IUV			20			
h _{fe}	Small signal forward	V _{CE} = 10 V	I _C = 0.5 A	f = 1 MHz	3			
	current transfer ratio	VCE = 10 V			3			

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300 \mu s$, duty cycle $\leq 2\%$.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER			МАХ	UNIT
R _{0JC} Junction to case thermal resistance			1.56	°C/W
R _{0JA} Junction to free air thermal resistance			35.7	°C/W

resistive-load-switching characteristics at 25°C case temperature

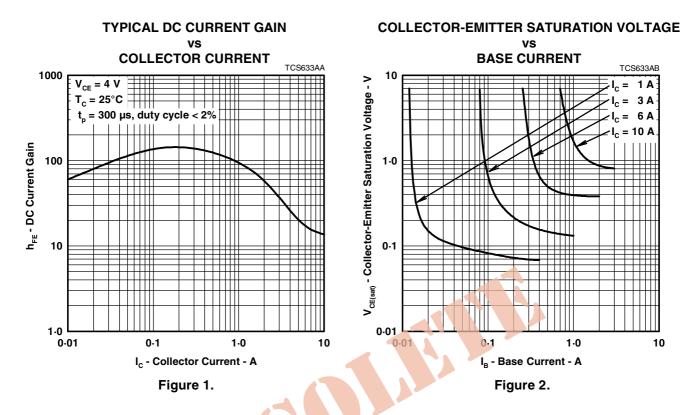
	PARAMETER	TEST CONDITIONS [†]			MIN	ТҮР	MAX	UNIT
t _{on}	Turn-on time	I _C = 6 A	I _{B(on)} = 0.6 A	$I_{B(off)} = -0.6 A$		0.6		μs
t _{off}	Turn-off time	$V_{BE(off)} = -4 V$	$R_L = 5 \Omega$	t_p = 20 µs, dc \leq 2%		1		μs

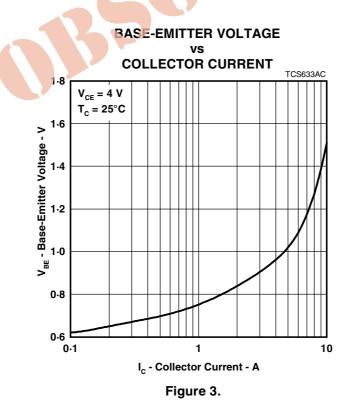
[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.



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TYPICAL CHARACTERISTICS



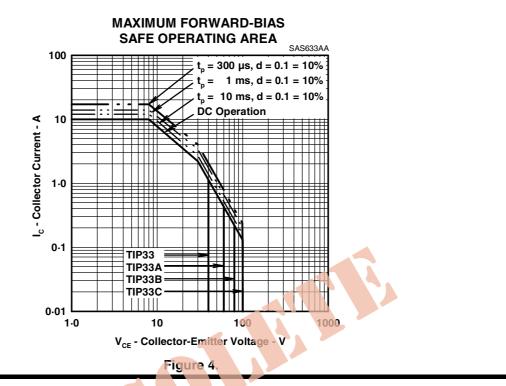


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BOURNS®

MAXIMUM SAFE OPERATING REGIONS



THERMAL INFORMATION

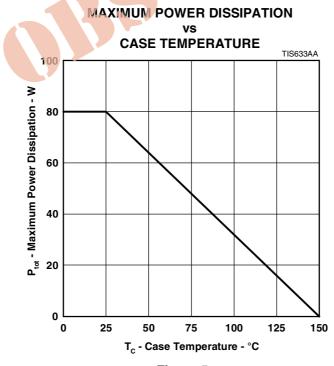


Figure 5.

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